TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

# SSM6N15FE

# **High Speed Switching Applications Analog Switching Applications**

Small package

:  $R_{on} = 4.0 \Omega (max) (@V_{GS} = 4 V)$ :  $R_{on} = 7.0 \Omega (max) (@V_{GS} = 2.5 V)$ Low ON resistance

### Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		$V_{DS}$	30	V	
Gate-Source voltage		V <sub>GSS</sub>	±20	(y)	
Drain current	DC	I <sub>D</sub>	100	(mA)	
	Pulse	I <sub>DP</sub>	200	IIIA	
Drain power dissipation (Ta = 25°C)		P <sub>D</sub> (Note 1)	150	WW	
Channel temperature		T <sub>ch</sub>	150	> °C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

Note:

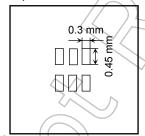
Marking

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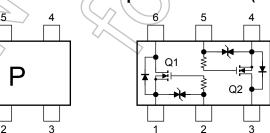
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure

Total rating, mounted on FR4 board (25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 0.135 mm<sup>2</sup>

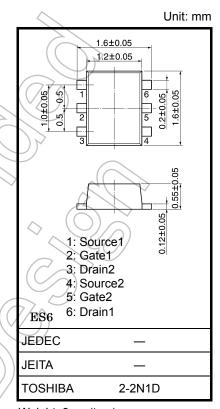


### Equivalent Circuit (top view)



### **Handling Precaution**

When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

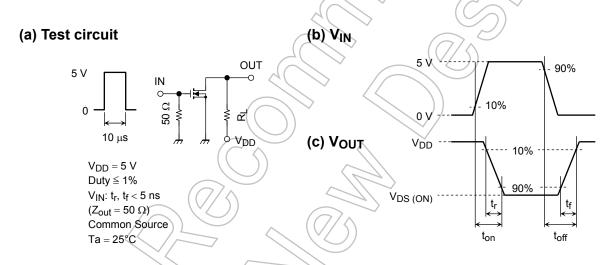


Weight: 3mg (typ.)

## Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current		I <sub>GSS</sub>	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	_	_	±1	μА	
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30	_	_	V	
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0	/	_	1	μА	
Gate threshold voltage		$V_{th}$	$V_{DS} = 3 \text{ V}, I_D = 0.1 \text{ mA}$	0.8	_	1.5	V	
Forward transfer admit	tance	Y <sub>fs</sub>	$V_{DS} = 3 \text{ V}, I_D = 10 \text{ mA}$	25	) )^_		mS	
Drain-Source ON resistance		R <sub>DS (ON)</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 4 V	) <u> </u>	2.2	4.0	Ω	
			I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 2.5 V	$\mathcal{D}$	4.0	7.0	7.2	
Input capacitance		C <sub>iss</sub>		)	7.8		pF	
Reverse transfer capacitance		C <sub>rss</sub>	$V_{DS} = 3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	3.6	_	pF	
Output capacitance		Coss		_	8.8		pF	
Switching time	Turn-on time	t <sub>on</sub>	$V_{DD} = 5 \text{ V}, I_D = 10 \text{ mA},$		50	$\rightarrow$	20	
	Turn-off time	t <sub>off</sub>	V <sub>GS</sub> = 0~5 V	-6	180	> —	ns	

# **Switching Time Test Circuit**



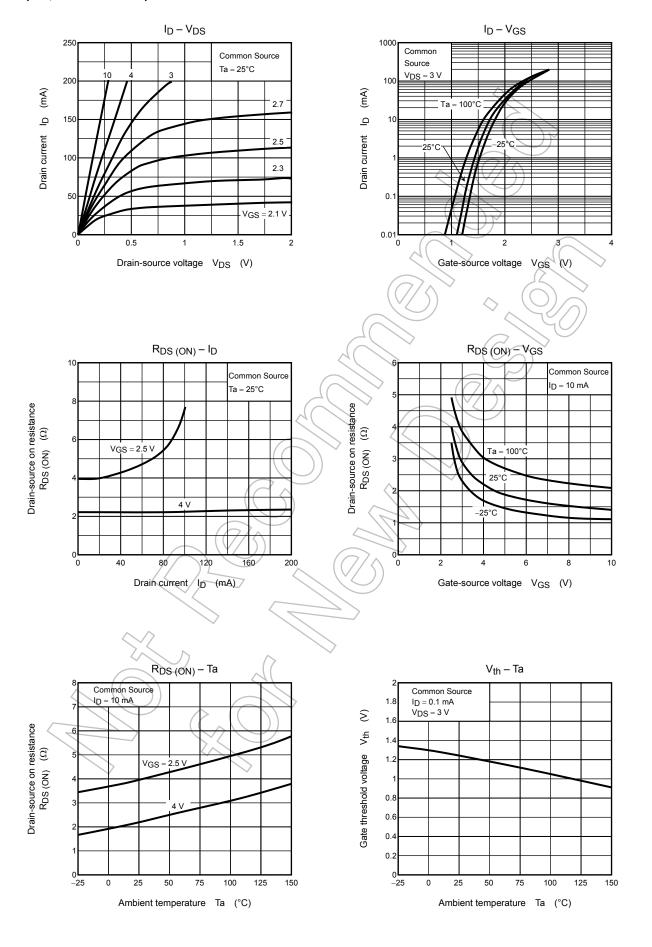
### **Precaution**

 $V_{th}$  can be expressed as voltage between gate and source when low operating current value is  $I_D$  = 100  $\mu A$  for this product. For normal switching operation,  $V_{GS}$  (on) requires higher voltage than  $V_{th}$  and  $V_{GS}$  (off) requires lower voltage than  $V_{th}$ . (Relationship can be established as follows:  $V_{GS}$  (off) <  $V_{th}$  <  $V_{GS}$  (on))

Please take this into consideration for using the device.

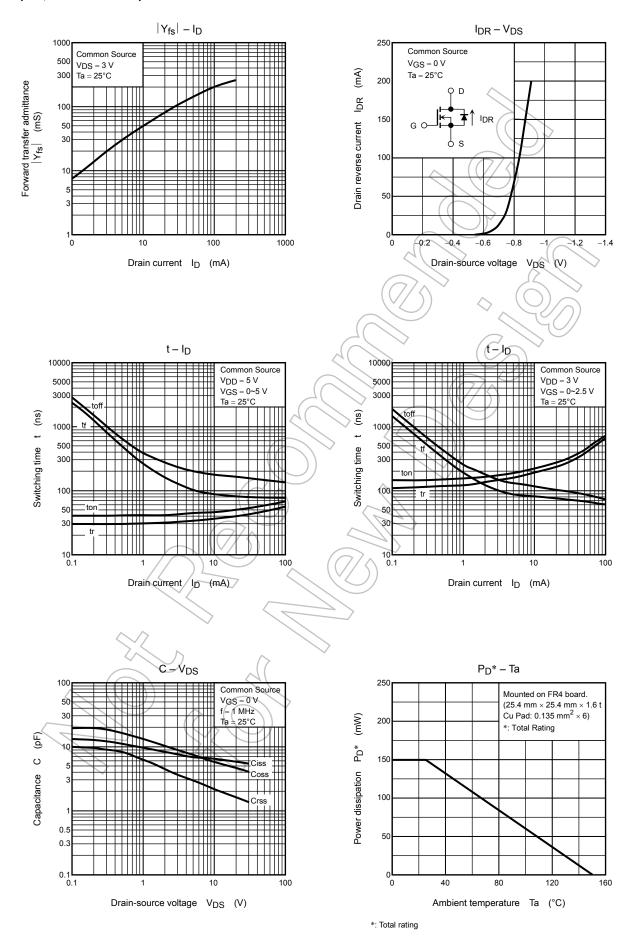
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### (Q1, Q2 Common)



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### (Q1, Q2 Common)



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